

PBHV9040X,115 Datasheet



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DiGi Electronics Part Number PBHV9040X,115-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number PBHV9040X,115

Description TRANS PNP 400V 0.25A SOT89

Detailed Description Bipolar (BJT) Transistor PNP 400 V 250 mA 55MHz 1

.5 W Surface Mount SOT-89



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
PBHV9040X,115	Nexperia USA Inc.
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
PNP	250 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
400 V	200mV @ 20mA, 100mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
100nA	80 @ 100mA, 10V
Power - Max:	Frequency - Transition:
1.5 W	55MHz
Operating Temperature:	Grade:
150°C (TJ)	Automotive
Qualification:	Mounting Type:
AEC-Q100	Surface Mount
Package / Case:	Supplier Device Package:
TO-243AA	SOT-89
Base Product Number:	
PBHV9040	

Environmental & Export classification

8541.29.0075

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	

1. General description

PNP high-voltage low V_{CEsat} transistor in a SOT89 (SC-62) medium power and flat lead Surface-Mounted Device (SMD) plastic package.

NPN complement: PBHV8540X

2. Features and benefits

- High voltage
- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability I_C and I_{CM}
- High collector current gain (h_{FE}) at high I_C

3. Applications

- · Electronic ballast for fluorescent lighting
- LED driver for LED chain module
- LCD backlighting
- High Intensity Discharge (HID) front lighting
- Automotive motor management
- · Hook switch for wired telecom
- · Switch mode power supply

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CESM}	collector-emitter peak voltage	V _{BE} = 0 V	-	-	-500	V
V _{CEO}	collector-emitter voltage	open base	-	-	-400	V
I _C	collector current		-	-	-0.25	Α
h _{FE}	DC current gain	V_{CE} = -10 V; I_{C} = -50 mA; T_{amb} = 25 °C	100	200	-	



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	Е	emitter		С
2	С	collector		В
3	В	base	3 2 1 SOT89	E sym079

6. Ordering information

Table 3. Ordering information

Type number	Package						
	Name	Description	Version				
PBHV9040X		plastic, surface-mounted package; 3 leads; 1.5 mm pitch; 4.5 mm x 2.5 mm x 1.5 mm body	SOT89				

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PBHV9040X	%4E

[1] % = placeholder for manufacturing site code

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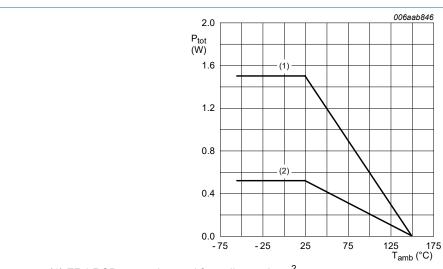
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	-500	V
V _{CEO}	collector-emitter voltage	open base		-	-400	V
V _{CESM}	collector-emitter peak voltage	V _{BE} = 0 V		-	-500	V
V _{EBO}	emitter-base voltage	open collector		-	-6	V
I _C	collector current			-	-0.25	Α
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-0.5	Α
I _{BM}	peak base current			-	-200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	0.52	W
			[2]	-	1.5	W
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

- Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².



- (1) FR4 PCB, mounting pad for collector 6 ${\rm cm}^2$
- (2) FR4 PCB, standard footprint

Fig. 1. Power derating curves

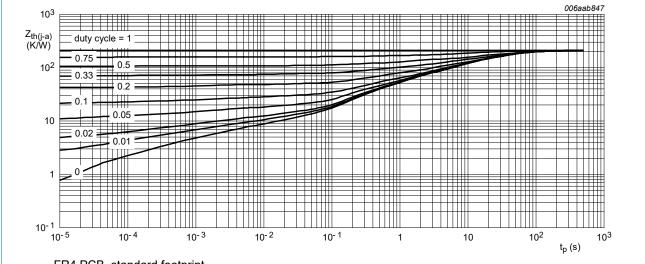
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9. Thermal characteristics

Table 6. Thermal characteristics

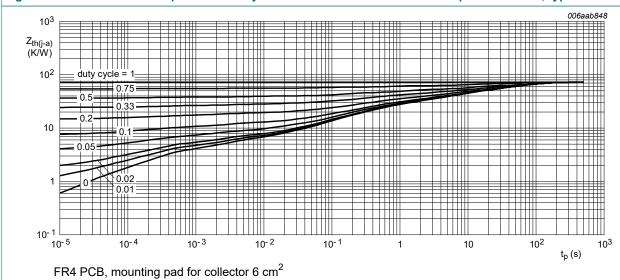
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from	in free air	[1]	-	-	240	K/W
junction to ambient		[2]	-	-	83	K/W	
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	-	20	K/W

- Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².



FR4 PCB, standard footprint

Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	V _{CB} = -320 V; I _E = 0 A; T _{amb} = 25 °C	-	-	-100	nA
current		V _{CB} = -320 V; I _E = 0 A; T _j = 150 °C	-	-	-10	μA
I _{CES}	collector-emitter cut-off current	V _{CE} = -320 V; V _{BE} = 0 V; T _{amb} = 25 °C	-	-	-100	nA
I _{EBO}	emitter-base cut-off current	V _{EB} = -4 V; I _C = 0 A; T _{amb} = 25 °C	-	-	-100	nA
h _{FE}	DC current gain	V _{CE} = -10 V; I _C = -50 mA; T _{amb} = 25 °C	100	200	-	
		V _{CE} = -10 V; I _C = -100 mA; T _{amb} = 25 °C	80	200	-	
		V_{CE} = -10 V; I_{C} = -250 mA; pulsed; $t_{p} \le$ 300 μs; $δ \le$ 0.02; T_{amb} = 25 °C	10	25	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -100 \text{ mA}; I_B = -20 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$	-	-110	-200	mV
V_{BEsat}	base-emitter saturation voltage	I_C = -100 mA; I_B = -20 mA; pulsed; $t_p \le$ 300 μs; $\delta \le$ 0.02; T_{amb} = 25 °C	-	-1	-1.1	V
t _d	delay time	V _{CC} = -2 V; I _C = -0.15 A; I _{Bon} = -0.03 A;	-	9	-	ns
t _r	rise time	I _{Boff} = 0.03 A; T _{amb} = 25 °C	-	1810	-	ns
t _{on}	turn-on time		-	1819	-	ns
t _s	storage time		-	715	-	ns
t _f	fall time		-	1085	-	ns
t _{off}	turn-off time		-	1800	-	ns
f _T	transition frequency	V_{CE} = -10 V; I_{C} = -10 mA; f = 100 MHz; T_{amb} = 25 °C	-	55	-	MHz
C _c	collector capacitance	V _{CB} = -20 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	7	-	pF
C _e	emitter capacitance	V _{EB} = -0.5 V; I _C = 0 A; i _c = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	150	-	pF

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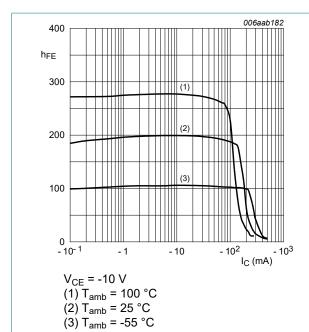


Fig. 4. DC current gain as a function of collector current; typical values

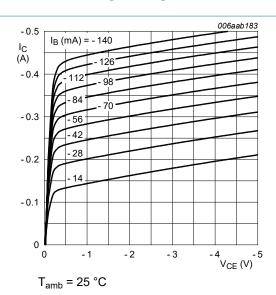


Fig. 5. Collector current as a function of collectoremitter voltage; typical values

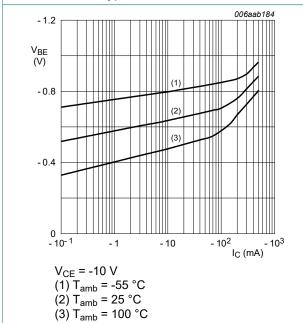
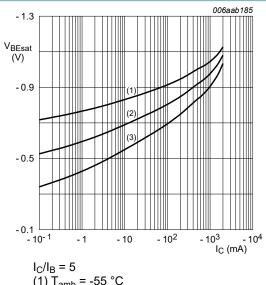


Fig. 6. Base-emitter voltage as a function of collector current; typical values



 $I_{C}/I_{B} = 5$ (1) $T_{amb} = -55 \,^{\circ}\text{C}$ (2) $T_{amb} = 25 \,^{\circ}\text{C}$ (3) $T_{amb} = 100 \,^{\circ}\text{C}$

Fig. 7. Base-emitter saturation voltage as a function of collector current; typical values

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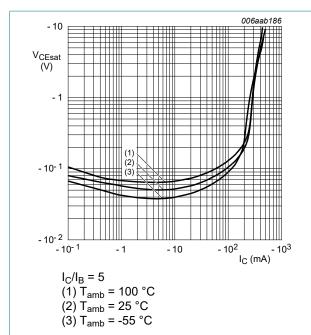


Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values

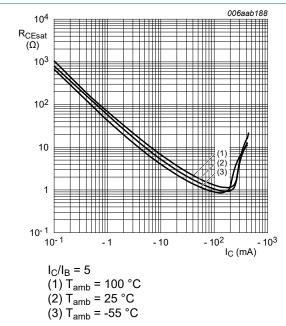


Fig. 10. Collector-emitter saturation resistance as a function of collector current; typical values

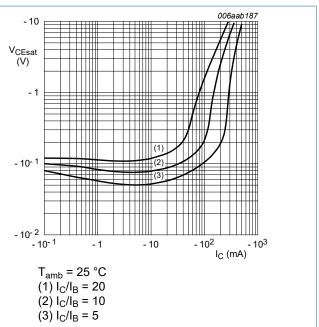


Fig. 9. Collector-emitter saturation voltage as a function of collector current; typical values

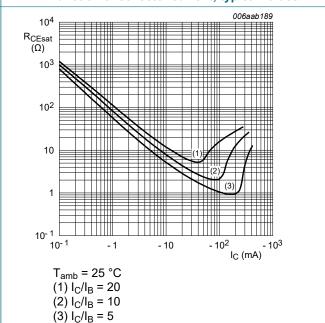


Fig. 11. Collector-emitter saturation resistance as a function of collector current; typical values

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11. Test information

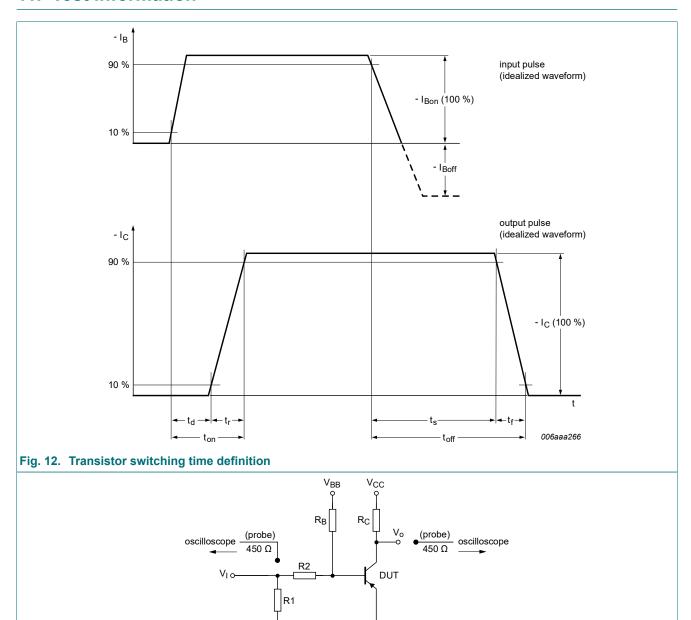
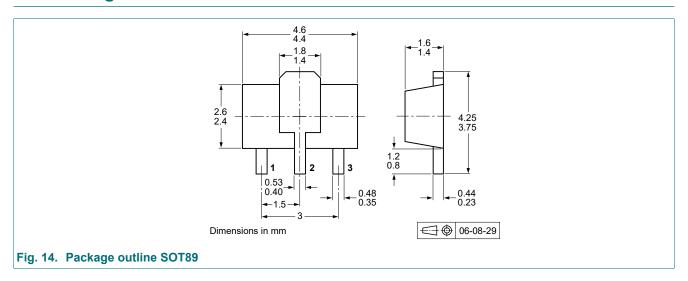


Fig. 13. Test circuit for switching times

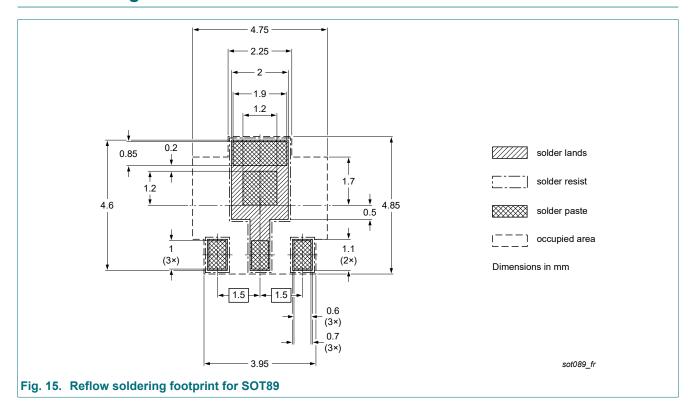
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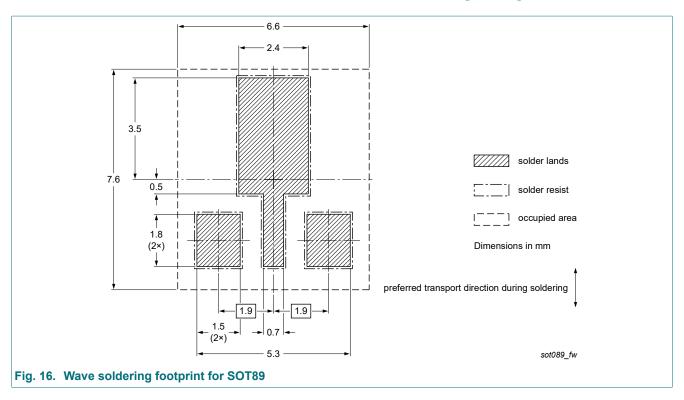
12. Package outline



13. Soldering



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14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PBHV9040X v.3	20241008	Product data sheet	-	PBHV9040X v.2			
Modifications:	 Product(s) changed to non-automotive qualification. Please refer to nexperia.com for automotive (-Q) product alternative(s). 						
PBHV9040X v.2	20230717	Product data sheet	-	PBHV9040X v.1			
PBHV9040X v.1	20131209	Product data sheet	-	-			

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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